



SBOS376A - NOVEMBER 2006

Low-Noise, High-Precision, JFET-Input, **OPERATIONAL AMPLIFIER**

FEATURES

OFFSET: 250μV (max)

DRIFT: 1μV/°C

LOW NOISE: 4.5nV/√Hz at 1kHz

BANDWIDTH: 18MHz SLEW RATE: 22V/us **BIAS CURRENT: 3pA**

QUIESCENT CURRENT: 4.5mA/Ch WIDE SUPPLY RANGE: ±4V to ±18V SINGLE PACKAGES: MSOP-8, SO-8 **DUAL PACKAGES: TSSOP-8. SO-8**

APPLICATIONS

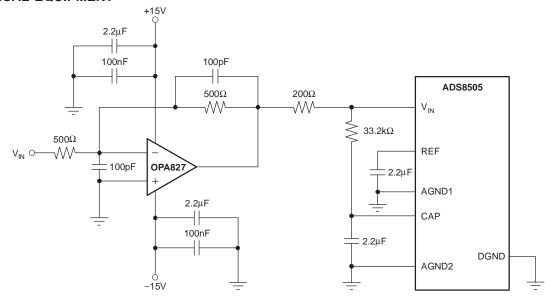
- PRECISION ±10V INPUT FRONT-ENDS
- TRANSIMPEDANCE AMPLIFIERS
- **INTEGRATORS**
- **ACTIVE FILTERS**
- A/D CONVERTER DRIVERS
- DAC OUTPUT BUFFERS
- **HIGH-PERFORMANCE AUDIO**
- PROCESS CONTROL
- **TEST EQUIPMENT**
- **MEDICAL EQUIPMENT**

DESCRIPTION

The OPA827 series of JFET operational amplifiers combines outstanding dc precision with excellent ac performance. It offers 100µV of offset, very low drift (1μV/°C) over temperature, low bias currents, and very low flicker noise of 400nV_{PP} (0.1Hz to 10Hz). It operates over a very wide supply voltage range of ±4V to ±18V on a low 4.5mA supply current. A dual version is also available for the OPA827 family.

Excellent ac characteristics, such as 18MHz gain bandwidth (GBW) and 22V/us slew rate, and precision dc characteristics make the OPA827 series well-suited for a wide range of applications such as 16- to 18-bit data acquisition systems, transimpedance (I/V-conversion) amplifiers, filters, precision ±10V front-ends, professional audio applications.

The single version (OPA827) is available in both MSOP-8 and standard SO-8 surface-mount packages. The dual version (OPA2827) is available in the small TSSOP-8 and in the standard SO-8 packages. All versions are specified from -40° C to $+125^{\circ}$ C.





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ABSOLUTE MAXIMUM RATINGS(1)

Supply Voltage ±20V
Signal Input Terminals, Voltage(2) (V–)–0.7 to (V+)+0.7V
Current(2) ±10mA
Differential Input Voltage TBD V
Output Short-Circuit ⁽³⁾ Continuous
Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Junction Temperature

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.7V beyond the supply rails should be current-limited to 10mA or less.
- (3) Short-circuit to ground, one amplifier per package.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe

proper handling and installation procedures can cause damage.

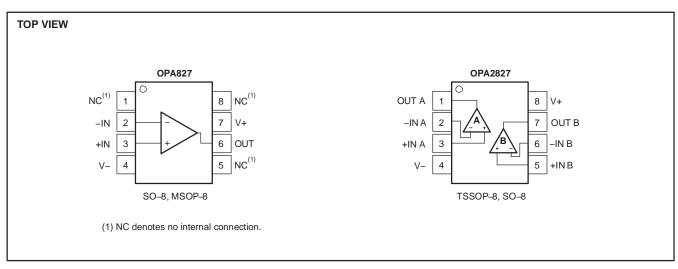
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING	
Low Grade	•	·		
00100-1	SO-8	D	OPA827A	
OPA827A	MSOP-8	DGK	TBD	
	SO-8	D	OPA2827A	
OPA2827A	TSSOP-8	PW	TBD	
High Grade	•	·		
OD40071	SO-8	D	OPA827	
OPA827I	MSOP-8	DGK	TBD	
0010000	SO-8	D	OPA2827	
OPA2827I	TSSOP-8	PW	TBD	

⁽¹⁾ For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

PIN CONFIGURATIONS





ELECTRICAL CHARACTERISTICS: $V_S = \pm 4V$ to $\pm 18V$

BOLDFACE limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to +125°C.

At $T_A = +25$ °C, $R_L = 10$ k Ω connected to $V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

At 1A = +25°C, RL = 10kt2 connec		OPA827A, OPA2827A			OPA827I, OPA2827I			
PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
OFFSET VOLTAGE								
Input Offset Voltage VOS	$V_{CM} = 0V, V_{S} = \pm 15V$		TBD	250		TBD	TBD	μV
Drift dV _{OS} /dT	10101 11, 13 =111		1	3.5		TBD	TBD	μ V/ °C
vs Power Supply PSRR	$V_S = \pm 4V \text{ to } \pm 18V, V_{CM} = 0V$		TBD	10		TBD	TBD	μV/V
Over Temperature	$V_S = \pm 4V \text{ to } \pm 18V, V_{CM} = 0V$			30			TBD	μ V/V
Channel Separation, dc	O W		TBD			TBD		μV/V
INPUT BIAS CURRENT								i i
Input Bias Current IB			±3	TBD		*	TBD	pA
Over Temperature			TBD	TBD		TBD	TBD	pA
Input Offset Current IOS			±3	TBD		*	TBD	pA
NOISE								
Input Voltage Noise f=0.1 to 10Hz en	$V_S = \pm 18V, V_{CM} = 0V$		0.4			*		μVpp
Input Voltage Noise Density		İ	İ					ĺ
f = 1kHz e _n	$V_S = \pm 18V, V_{CM} = 0V$		4.5			*		nV/√ Hz
f = 10kHz e _n	$V_S = \pm 18V, V_{CM} = 0V$		4.5			*		nV/√ Hz
Input Current Noise Density								
f = 1kHz i _n	$V_S = \pm 18V, V_{CM} = 0V$		TBD			*		fA/√ Hz
INPUT VOLTAGE RANGE								
Common-Mode Voltage Range V _{CM}		(V-)+2.5		(V+)-2.5	*		*	V
Common-Mode Rejection Ratio CMRR	$(V-)+2.5V < V_{CM} < (V+)-2.5V$	108			TBD			dB
Over Temperature			TBD			TBD		dB
INPUT IMPEDANCE								
Differential			10 ¹³ TBD			*		$\Omega \parallel pF$
Common-Mode			10 ¹³ 7			*		Ω pF
OPEN-LOOP GAIN								
Open-Loop Voltage Gain A _{OL}	$R_L = 1k\Omega$, $(V-)+2.75V < V_O < (V+)-2.1V$	114	120		TBD	TBD		dB
Over Temperature	$R_L = 1k\Omega$, $(V-)+2.75V < V_O < (V+)-2.1V$	108	TBD		TBD	TBD		dB
FREQUENCY RESPONSE	C _L = 100pF							
Gain-Bandwidth Product GBW			18			*		MHz
Slew Rate SR	G = +1		22			*		V/μs
Settling Time, 0.1% ts	4V Step, G = +1		TBD			*		ns
0.01% (16-bit)	4V Step, G = +1		TBD			*		ns
Overload Recovery Time	V _{IN} • Gain > V _S		TBD			*		μs
Total Harmonic Distortion THD+N + Noise	G = +1, f = 1kHz		TBD			*		%
OUTPUT								
Voltage Output Swing from Rail	$R_L = 1k\Omega$, $A_{OL} > 114dB$	(V-)+2.75		(V+)-2.1	*		*	V
Over Temperature	R _L = 1kΩ, A _{OL} > 108dB	(V-)+2.75		(V+)-2.1	*		*	V
Output Current I _{OUT}	V _S - V _{OUT} < 1.5V		30			*		mA
Short-Circuit Current I _{SC}			±40			*		mA
Capacitive Load Drive C _{LOAD}			TBD			TBD		pF

NOTE: * indicates same specifications as for low-grade version of device.



ELECTRICAL CHARACTERISTICS: $V_S = \pm 4V$ to $\pm 18V$ (continued)

BOLDFACE limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

At TA = +25°C, RL = 10k Ω connected to Vg/2, and VOUT = Vg/2, unless otherwise noted.

			OPA827A, OPA2827A		OPA827I, OPA2827I				
PARAMETER		CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
POWER SUPPLY									
Specified Voltage	V_S		±4		±18	*		*	V
Quiescent Current (per amp.)	ΙQ	I _O = 0		4.5	TBD		*	*	mA
Over Temperature					TBD			*	mA
TEMPERATURE RANGE									
Specified Range			-40		+125	*		*	°C
Operating Range			-55		+125	*		*	°C
Thermal Resistance	$\theta_{\sf JA}$								
SO-8, MSOP-8, TSSOP-8				150			*		°C/W

NOTE: * indicates same specifications as for low-grade version of device.



PACKAGE OPTION ADDENDUM

22-Nov-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins I	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
OPA827AID	PREVIEW	SOIC	D	8	75	TBD	Call TI	Call TI
POPA827AID	PREVIEW	SOIC	D	8	1500	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

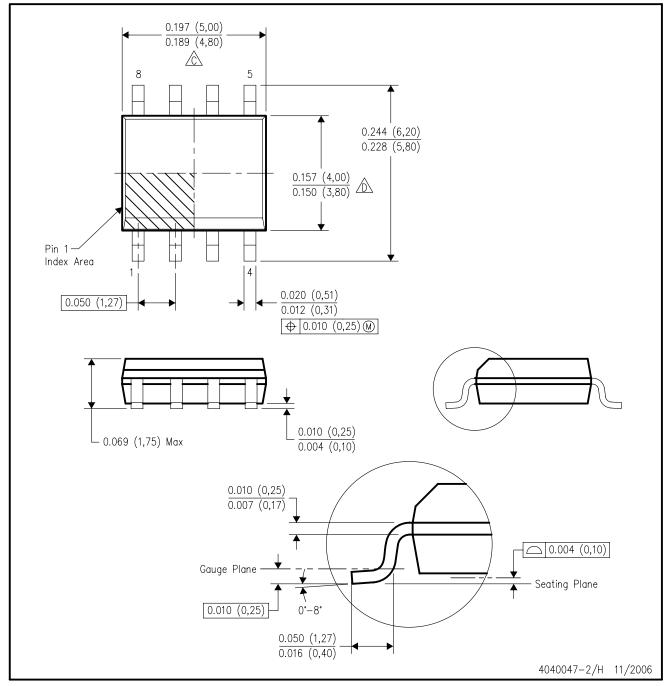
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

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